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Investigating the gas phase emitter effect of caesium and cerium in ceramic metal halide lamps in dependence on the operating frequency

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Abstract. The work function and with it the temperature of tungsten electrodes in HID lamps can be lowered and the lifetime of lamps increased by the gas phase emitter effect. A determination of the emitter effect of *Cs* and *Ce* is performed by phase resolved measurements of the electrode tip temperature $T_{tip}(\varphi)$, plasma temperature $T_{pl}(\varphi)$ and particle densities $N(\varphi)$ by means of pyrometric, optical emission and broadband absorption spectroscopy in dependence on the operating frequency. The investigated HID lamps are ceramic metal halide lamps with transparent discharge vessels made of YAG, filled with a buffer gas consisting of *Ar*, *Kr* and predominantly *Hg* and seeded with *CsI* or *CeI₃*. In the YAG lamp seeded with *CsI* and *CeI₃* as well as in a YAG lamp seeded with *DyI₃* (corresponding results can be found in a preceding paper) a gas phase emitter effect is observed in the cathodic phase due to a *Cs*, *Ce* or *Dy* ion current. In the YAG lamp seeded with *CsI* the phase averaged coverage of the electrode surface with emitter atoms decreases and the electrode temperature rises with increasing frequency, whereas the emitter effect of *Ce* and *Dy* is extended to the anodic phase, which leads to a decreased average temperature $T_{tip}(\varphi)$ with increasing frequency. This different behaviour of the averaged values of $T_{tip}(\varphi)$ for increasing frequency is caused by the differing adsorption energies E_a of the respective emitter materials. In spite of the influence of E_a on the coverage of the electrode with emitter atoms, the cathodic gas phase emitter effect produces in the YAG lamps seeded with *CsI*, *CeI₃* and *DyI₃* a general reduction of the electrode tip temperature $T_{tip}(\varphi)$ in comparison to a YAG lamp with *Hg* filling only.

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1. Introduction

Ceramic metal halide lamps offer presently the cheapest option to realize a point shaped light source with an output of more than one k-lumen satisfying the requirements of an efficacy of more than 100 lm/W, a life time of more than 10000 h and a colour rendering index higher than 90 cri. But the high thermal load of the electrodes, resulting in a high electrode temperature, is a quite serious problem with this special version of HID lamps.

The electrode temperature, both of the cathode and of the anode, is mainly determined by the work function of the electrode material [1, 2, 3, 4, 5, 6, 7, 8]. If pure tungsten electrodes are used the temperature of the electrode tip is raised up to its melting point, $T_m = 3695$ K, to supply a sufficiently high thermionic electron emission for a diffuse attachment of the lamp arc on the electrodes [9, 10, 11, 12, 13, 14, 15]. But the work function and with it the electrode temperature can be substantially reduced if a dipole layer consisting of a monolayer of atoms being electropositive with respect to tungsten is deposited on the tungsten surface. It lowers the potential barrier at the electrode surface for electrons leaving or entering the electrode.

Several techniques are applied to establish this so called emitter effect in HID lamps by a monolayer of electropositive atoms [16]. Doping tungsten with ThO_2 is the most traditional method to cover the electrode surface with a dipole layer of thorium atoms dated from Langmuir [17]. According to the experience in vacuum electronics it is assumed that the monolayer is formed by the diffusion of thorium from the interior of the electrode, after dissociation of ThO_2 into Th metal and oxygen [18]. But this simple view is doubtful in the case of HID lamp electrodes since detailed investigations on thoriated electrodes have revealed that only HID cathodes show an emitter effect [2, 19] but not HID anodes [6, 7]. Another method to reduce the work function is realised by depositing emitter material within the interspaces of a closely wound tungsten coil ending up in some distance from the electrode tip. When the electrode is heated up the emitter material, e.g. barium, diffuses along the electrode surface to the tip [20, 21].

The most versatile approach is the gas phase emitter effect, in which case the monolayer is deposited from the gas phase. The number of pure metals, which are appropriate to realize a gas phase emitter effect in HID lamps, is rather low. But the number of elements can be considerably extended, if the high vapour pressure of metal iodides is employed, e.g. that of rare earth iodides, to implement a gas phase emitter effect. In some cases a gas phase emitter effect is clearly realized, both at the cathode and at the anode, e.g. in high pressure sodium lamps, if appropriate lamp parameters are chosen [3, 8]. In other cases it may be confined to the cathode, at least if it is operated with a dc current. This situation seems to be present in a YAG lamp being seeded with DyI_3 and different other additives as NaI and TlI [22]. If HID lamps, which are seeded with ThI_4 [23], DyI_3 [24, 25] or other metal iodides are operated with an ac

or switched-dc current, it could not be decided definitely, whether the emitter effect is limited to the cathodic phase or also being effective within the anodic phase. To clarify this point, the gas phase emitter effect of *Dy* is investigated in a preceding paper [26] by spectroscopic measurements in front of the electrode and pyrometric measurements along the electrode rod in dependence on the operating frequency. These measurements have shown that the reduction of the electrode temperature is correlated to a high *Dy* ion density in front of the electrode within the cathodic phase, suggesting that the *Dy* monolayer is essentially sustained by a *Dy* ion current towards the cathode. But at higher operating frequencies a reduction of the work function is also effective within the anodic phase, as is shown by the reduction of the electrode temperature with increasing operating frequency. It may be attributed to the finite life time of the layer reflecting the adsorption energy of *Dy* on the tungsten surface of $E_a = 4.97$ eV.

If the hypothesis is valid that the atomic monolayer is mainly generated by an ion current towards the cathode then the gas phase emitter effect does not only depend on the reduction of the work function $\Delta\phi$ and the adsorption energy E_a of the atoms within the dipole layer but also on the ionisation energy E_i of the emitter material and the mobility $\mu_i \propto M_i^{-1}$ of the ions, on the electrode polarity and with it on the operating frequency. The reduction of the work function of tungsten ϕ_W may vary between $\Delta\phi = 0$ and $\Delta\phi = \phi_W - \phi_{emitter} + \delta\phi$ where $\phi_{emitter}$ is the work function of a surface consisting of many layers of emitter material and $\delta\phi$ represents a reduction of the work function in the order of several hundred meV if the coverage Θ of the tungsten surface is incomplete ($0.4 < \Theta < 1$) [27].

To clarify the role of the ion current the emitter effect of the alkali metal caesium and of the rare earth metal cerium are compared by measurements in YAG lamps performed at operating frequencies being varied from 1 Hz to 1 kHz. The buffer gas of the YAG lamps consisting of *Ar*, *Kr* and predominantly *Hg* is seeded either with *CsI* or *CeI₃*. Caesium is characterized by a work function $\phi_{Cs} = 1.8$ eV and an ionisation energy $E_i = 3.89$ eV, which is very favourable for the gas phase emitter effect, but also by a quite low adsorption energy $E_a = 3.37$ eV [28], which is counterproductive. Cerium

	work function ϕ	ionisation energy E_i	adsorption energy E_a	relative mass A_r
<i>Cs</i>	1.8 eV	3.89 eV	3.37 eV	132.90
<i>Ce</i>	2.7 eV	5.54 eV	6.84 eV	140.12
<i>Dy</i>	3.1 eV	5.92 eV	4.97 eV	162.50
<i>Tl</i>	3.7 eV	6.11 eV	3.28 eV	204.38

Table 1: Values for work function ϕ , ionisation energy E_i , adsorption energy E_a on a tungsten surface and relative mass A_r for *Cs*, *Ce*, *Dy* and *Tl* [28, 29, 30]

is characterized by $\phi_{Ce} = 2.7 \text{ eV}$, $E_i = 5.54 \text{ eV}$, values, which are less favourable than those of Cs but comparable with those of Dy, and $E_a = 6.84 \text{ eV}$ [29, 30], which is nearly by a factor of two higher than the adsorption energy of Cs and also higher than the adsorption energy of Dy. Since the relative masses of caesium ($A_r = 132.9$) and cerium ($A_r = 140.12$) are not very different, it may be assumed, that the mobility of the two ions is quite similar. Both a cerium ion current and a caesium ion current may generate within the cathodic phase a distinct emitter effect, but as a consequence of the different adsorption energies the life time of the Ce monolayer may be longer and therefore the dependence of the gas phase emitter effect of cerium on the operating frequency more pronounced than that of caesium. The data of ϕ , E_i , E_a and A_r of Cs, Ce and of Dy, Tl, by which the lamp was seeded in the preceding paper [26], are summarized in table 1.

To check this speculation the electrode temperature within the YAG lamps and the densities of the emitter materials in front of the YAG lamp electrodes are investigated in dependence on the operating frequency. In the case of the YAG lamp seeded with CsI the same measuring methods as in [26] are applied. The electrode temperature as well as the plasma temperature and the Cs atom density are determined by emission spectroscopy. The Cs ion density can not be measured since an appropriate Cs ion line is not available. But it is calculated taking into account that LTE is realized. In the case of the YAG lamp seeded with CeI₃ for the electrode temperature as well as for the Ce atom density new measuring methods are applied, which give more reliable results than the previous ones. The 2D distribution of the electrode temperature is recorded by a photograph with a CCD camera, which is calibrated for the infrared wavelength of a narrowband interference filter in front of the camera [22]. The Ce atom density is determined by absorption spectroscopy. For this purpose the measuring system for emission spectroscopy is supplemented by an intense back light, realized by an UHP lamp [20, 21, 31].

2. Experimental set up

2.1. YAG lamp

The lamps under investigation are special research HID lamps with simple rod-type pure tungsten electrodes with a diameter of 0.36 mm, a length of 5 mm, an inter electrode spacing of 7 mm and an ovoid-shaped discharge vessel made of yttrium alumina garnet (Y₆Al₅O₁₂) shortened YAG [22]. YAG is a transparent ceramic and therefore suitable for optical observations. The YAG vessel is placed inside a sealed and evacuated outer bulb, made of fused silica doped with lead, for protection from UV light, mechanical protection and thermal insulation of the inner bulb. The discharge vessel is filled with a buffer gas, which consists of an argon-krypton-mixture (30 kPa), and with 6 mg mercury to generate a background pressure of 2 MPa during lamp operation being required for a sufficiently high power input into the arc. 1 mg of the respective emitter element (CsI,

CeI_3 , DyI_3 , TlI) is added to the lamp filling to generate a gas phase emitter effect. A lamp without any emitter material is used as reference. The results which are obtained by the lamp seeded with DyI_3 and the reference lamp are already published in [26] (figure 3-5 and figure 1-2).

A sketch of the inner tube of a YAG lamp is shown in figure 1 while the filling properties of all YAG lamps presented in this work and in the preceding paper consulted for comparison [26] are listed in table 2.

Figure 1: Schematic drawing of the inner tube of a YAG lamp

Lamp type	Hg (mg)	Total salt (mg)	Metal halide salt			
			CsI (mol%)	CeI_3 (mol%)	DyI_3 (mol%)	TlI (mol%)
Hg	6	0	0	0	0	0
Cs	6	1	100	0	0	0
Ce	6	1	0	100	0	0
Dy	6	1	0	0	100	0
Tl/Dy	6	2	0	0	50	50

Table 2: Properties of the filling of YAG lamps presented in this work and in the preceding paper consulted for comparison [26]

The YAG lamps, built for a nominal input power of 70 W, are operated in vertical position. Since the accumulation of the liquid salt at the bottom of the discharge vessel hampers optical observations, all optical measurements are performed at the upper electrode. The investigated lamps are operated with switched-dc current at 0.8 A and frequencies of 1, 10, 100, 500 Hz and 1 kHz by a voltage controlled current source (*Feucht*

Figure 2: Schematic drawing of the complete optical set up

Elektronik DCU/I 2250-28, max. voltage: 400 V, max. current: 28 A, max. power: 2250 VA) which is controlled by a voltage from a signal generator (*Agilent* 33120A).

2.2. Measuring system for phase resolved emission and absorption spectroscopy

A schematic drawing of the optical set up is shown in figure 2. To determine the axial electrode temperature profile within the YAG lamp seeded with CeI_3 the upper electrode of the YAG lamp is focused on a CCD camera (*PCO Sensicam Fastshutter*) by means of a zoom objective (*Navitar Zoom 6000*). The record is controlled by an electro-mechanical shutter (*Uniblitz VS14*) in front to avoid the undesirable smear effect [32]. A narrow bandpass filter at 890 nm (10 nm FWHM) between the CCD camera system and the YAG lamp is used for recording a two dimensional image at the particular wavelength. By calibration with a tungsten ribbon lamp (*Wi17g3*) from *OSRAM* absolute electrode temperatures $T_{el}(z)$ are deduced from the camera picture. Furthermore, the shape of the arc attachment can be extracted from the images. This 2D-method was presented in [22] for the first time. By replacing the infrared filter in front of the CCD camera by a neutral density filter (*Newport*) it is also possible to record more detailed images of the arc attachment.

Optical emission spectroscopy is realised by a 1/4 m spectrograph (*Chromex 250is*, grating: 1200 lines/mm) and a second CCD camera (*PCO Sensicam QE*). Two lenses (focus length of 310 mm, respectively) project a 1:1 image of the lamp on the entrance slit of the spectrograph. A rotatable so-called Dove prism between the two lenses is used for turning the image around the optical axis.

To measure the axially resolved electrode temperature $T_{el}(z)$ spectroscopically, the upper electrode within the YAG lamp seeded with CsI has to be adjusted by means

of the prism parallel to the entrance slit of the spectrograph (slit width: $100\text{ }\mu\text{m}$). An edge filter at 600 nm is positioned in front of the entrance slit to suppress radiation from the second order spectrum produced by the grating at $\lambda_{meas}/2$. Measurements of $T_{el}(z)$ are performed at a single suitable wavelength in the infrared region where at best no plasma radiation is present. After a calibration with the tungsten ribbon lamp, absolute temperature values are received.

To determine the plasma temperature T_{pl} and particle densities of atoms N_a and ions N_i in front of the electrode, the emission of a discharge cross section at a fixed distance from the electrode tip has to be captured by the entrance slit of the spectrograph (slit width: $25\text{ }\mu\text{m}$). For this purpose the image of the upper lamp electrode is adjusted perpendicular to the slit by turning the Dove prism through 45° around the optical axis. The intensities, recorded by the CCD camera at wavelengths from approximately 350 nm to 950 nm , are calibrated in absolute units by means of the tungsten ribbon lamp. Radial resolved measurements of T_{pl} , N_a and N_i are performed in this work $125\text{ }\mu\text{m}$ in front of the upper electrode. They are accomplished by an evaluation of radial distributions of line emission coefficients from measured lateral line intensity distributions by an inverse Abel transformation.

A more detailed description of the measuring system for emission spectroscopy can be found in [14, 24, 26, 33].

To measure particle densities by absorption spectroscopy the set up for emission spectroscopy is extended by a back light source being positioned behind the YAG lamp on the elongation of the optical axis [20, 21, 31]. A powerful broadband light source with a high radiance within the visible spectral range and a temporarily very stable emission is realized with an ultra high pressure (UHP) lamp [34]. The UHP lamp (*Philips 228 L4*), originally designed for video projection systems, is electrically driven by the electronic circuit from a video projector. It is operated with a 90 Hz switched-dc current. Its amplitude amounts to 2.2 A and the electrical power input to 120 W . A specially designed reflector is already equipped around the UHP lamp so that a maximal light power is emitted as a quasi-parallel light beam by the lamp. To minimize the influence of the irradiation by the powerful UHP lamp on the operational conditions of the YAG lamp an optical bandpass filter (*Andover Corporation 50 mm*) is installed between both lamps. The filtered UHP light is focused by an achromatic lens (focus length of 80 mm) to an area with a diameter of $d = 10\text{ mm}$ around the measuring point. It provides a largely homogeneous radiance perpendicular to axis of the YAG lamp. The beam emanating from the UHP lamp is not strictly parallel within the tube of the YAG lamp as it is indicated in figure 2. But the angle of beam spread is so small and the optical path length within the discharge so short that the beam divergence can be neglected. A calibration of the optical signals with the tungsten ribbon lamp is unnecessary due to the special analysis of the measuring data presented in section 4.2. By the same reason the phase modulation of the light emission of the UHP lamp which is on the order of 2% has not to be considered.

All quantities are measured with some phase resolution. It corresponds to temporal resolution as long as the lamp operation is really periodic. It is accomplished by trigger signals for the cameras, which are shifted with an adjustable time delay with respect to a well defined reference phase angle. A reproducible reference phase angle can be deduced from zero crossing of the lamp voltage as it was shown by Langenscheidt [13]. To trigger the cameras only the rising edge of the lamp voltage is used. The uncertainty of the trigger pulse does not exceed $2\mu\text{s}$. A pulse delay generator (*Stanford Research Systems* DG 535) is used to shift the trigger signal from voltage zero crossing. A block diagram of the trigger set up can be found in [14].

Lamp type	Electrode temperature T_{el}	Plasma temperature T_{pl}	Atom density N_a	Ion density N_i
Hg	emission spectroscopy	emission spectroscopy	-	-
Cs	emission spectroscopy	emission spectroscopy	emission spectroscopy	Saha equation
Ce	2D-method	emission spectroscopy	absorption spectroscopy	emission spectroscopy
Dy	emission spectroscopy	emission spectroscopy	emission spectroscopy	emission spectroscopy
Tl/Dy	emission spectroscopy	emission spectroscopy	emission spectroscopy	emission spectroscopy

Table 3: Measuring methods used in this work and in [26] for electrode temperature T_{el} , plasma temperature T_{pl} and particle density measurements of atoms N_a and ions N_i of the respective emitter material *Cs*, *Ce* and *Dy*

In table 3 the different measuring methods used in this and in the reference work [26] are assigned to the lamp types given in table 2.

3. Pyrometric electrode temperature measurement (1 λ -method)

For accurate pyrometric temperature measurements a segment of the spectrum emitted by the electrode has to be chosen which is as far as possible in the infrared region but still in the sensitivity range of the CCD camera. In addition the plasma radiation emitted by the YAG lamp in the selected spectral range should be insignificant compared to the emission of the electrode surface. In the case of the YAG lamp seeded with *CsI* the emission of the electrode in the infrared is superimposed by an intense multi line emission of *Cs* [35]. Therefore a pyrometric measurement with a spectrograph is an

appropriate choice. An inspection of the spectrum showed that an applicable wavelength for this kind of temperature measurement is 745 nm. But in the case of a lamp seeded with CeI_3 both requirements are met within a spectral range around 890 nm as was checked spectroscopically. Therefore the 2D-method with an interference filter at 890 nm is the more favourable pyrometric measuring procedure.

The spectral radiance along the upper electrode $I_{el}(\lambda, z)$ at $\lambda = 745$ nm or $\lambda = 890$ nm is recorded by a single measurement at a selected phase angle φ . It is assumed that the spectral radiance emitted by the tungsten electrodes is represented by that of a grey body radiator $I_{gb}(\lambda, T_{el})$, which can be calculated in dependence on the temperature T_{el} and wavelength λ from Planck's law and the spectral emissivity of tungsten $\epsilon(\lambda, T_{el}) < 1$. Reliable spectral emissivities of tungsten are available in literature [36]. Axial temperature profiles $T_{el}(z, \varphi)$ are obtained by comparing $I_{el}(\lambda, z, \varphi)$ and $I_{gb}(\lambda, T_{el})$.

The surface roughness is enhanced by the arc attachment in the vicinity of the electrode tip and with it the emissivity is exaggerated in an undefined manner compared to the values given in literature. As a consequence the temperature measurement at the electrode tip becomes doubtful. In previous investigations of HID electrodes operated with a dc-current the axial electrode temperature distribution was additionally simulated by integrating the 1D heat balance of the electrode and matching it to the measured distribution within a region of confidence, in which the values of ϵ were trustable. The temperature of the electrode tip T_{tip} was then determined by an extrapolation of the integrated 1D heat balance. Reliable results were obtained with this method for electrodes operated with a dc-current [1, 6, 11]. But if the electrodes are operated with an ac-current the modulation of the electrode temperature is limited to a small area behind the electrode tip [15]. Therefore also the tip region with its exaggerated values of ϵ has to be taken into account when the integral of the heat balance is matched to the measured temperature distribution. A more realistic temperature profile can be used for the matching procedure if instead of a one dimensional a two dimensional temperature distribution is available. In this case it is easier to identify and remove locally excessive temperatures. A detailed discussion of the limited measuring accuracy of T_{tip} is presented in [15, 26]. It was shown that the phase resolved experimental determination of T_{tip} is afflicted with an error of the order of $\Delta T_{tip} \approx 50$ K.

4. Spectroscopic plasma temperature and particle density measurements

4.1. Emission spectroscopy

The spectral radiances $I_\nu(y)$ of optical thin lines are measured in a fixed distance d from the electrode tip along a y -axis perpendicular to the optical axis x and the discharge

axis z . They are calibrated in absolute units and integrated over line profiles, providing lateral distributions of line intensities $I_L(y)$. By an inverse Abel transformation of $I_L(y)$ radial emission coefficients $\epsilon_L(r)$ are obtained if the discharge is rotational symmetric.

$\lambda_1 = 576.96 \text{ nm}$	$\lambda_2 = 579.07 \text{ nm}$
$A_1 = 1.709 \cdot 10^8 \text{ s}^{-1}$	$A_2 = 2.039 \cdot 10^8 \text{ s}^{-1}$
$g_1 = 5$	$g_2 = 5$
$E_1 = 8.853 \text{ eV}$	$E_2 = 8.845 \text{ eV}$

Table 4: Spectroscopic data for the calculation of the plasma temperature T_{pl} from Hg-line intensities [38]

At first the plasma temperature T_{pl} inside a YAG lamp is determined using two overlapping mercury lines at $\lambda_1 = 576.96 \text{ nm}$ and $\lambda_2 = 579.07 \text{ nm}$ [15, 24, 37]. The corresponding spectroscopic data is given in table 4 with the transition probabilities A_1 and A_2 , the statistical weights g_1 and g_2 and the excitation energies of the upper line levels E_1 and E_2 . By assuming local thermal equilibrium, the common temperature of all particles, in this paper always named as plasma temperature T_{pl} , is calculated from the sum of the respective line emission coefficients postulating a Boltzmann population of the upper emitting states and using the ideal gas law.

$$\epsilon_{ul} = \frac{hc_0}{4\pi} \frac{p_0}{k_b T_{pl}} \frac{1}{Q_{Hg}(T_{pl})} \left[\frac{g_1 A_1}{\lambda_1} \exp\left(-\frac{E_1}{k_b T_{pl}}\right) + \frac{g_2 A_2}{\lambda_2} \exp\left(-\frac{E_2}{k_b T_{pl}}\right) \right] \quad (1)$$

A constant mercury pressure of $p_0 = 2 \text{ MPa}$ is assumed. A plasma temperature of $T_{pl} \leq 7000 \text{ K}$ with an error margin of about 4 % was found within YAG lamps with similar parameters using the two Hg-lines [24, 26].

The Cs atom density $N_{a,Cs}$ within the YAG lamp seeded with CsI and the Ce ion density $N_{i,Ce}$ within the lamp seeded with CeI_3 are evaluated by means of $\epsilon_L(r)$ of the respective atomic or ionic line, assuming a Boltzmann population of the emitting states defined by $T_{pl}(r)$. In both cases two overlapping lines are used. The sum of their emission coefficients is given by a formula as that for the two mercury lines (equation 1) in which the factor $p_0/k_b T_{pl}$ is exchanged by $N_{a,Cs}$ or $N_{i,Ce}$. The corresponding spectroscopic data for a determination of $N_{a,Cs}$ is presented in table 5 while the data for the evaluation of $N_{i,Ce}$ is given in table 6.

The complete measuring and data processing procedure is described in detail in [24, 26, 31, 33, 39].

The determination of the densities $N_{a,Cs}$ of Cs atoms and $N_{i,Ce}$ of Ce ions by emission spectroscopy is afflicted mainly with three different error sources: the

$\lambda_1 = 697.33 \text{ nm}$	$\lambda_2 = 698.35 \text{ nm}$
$A_1 = 7.514 \cdot 10^6 \text{ s}^{-1}$	$A_2 = 1.296 \cdot 10^6 \text{ s}^{-1}$
$g_1 = 6$	$g_2 = 4$
$E_1 = 3.232 \text{ eV}$	$E_2 = 3.230 \text{ eV}$

Table 5: Spectroscopic data for the calculation of Cs atom density $N_{a,Cs}$ [38]

$\lambda_1 = 457.23 \text{ nm}$	$\lambda_2 = 457.28 \text{ nm}$
$A_1 = 2.663 \cdot 10^7 \text{ s}^{-1}$	$A_2 = 1.515 \cdot 10^7 \text{ s}^{-1}$
$g_1 = 12$	$g_2 = 10$
$E_1 = 3.395 \text{ eV}$	$E_2 = 4.192 \text{ eV}$

Table 6: Spectroscopic data for the calculation of Ce ion density $N_{i,Ce}$ [38]

measuring inaccuracy of the emission coefficient ϵ_{ul} , which amounts at least 20 %, the uncertainty of the transition probabilities of at least 10 % and the measuring error of the plasma temperature T_{pl} of 4 %, which is multiplied by a factor $E_u/k_b T_{pl}$ being on the order of 5 - 7. The error sources are discussed in more detail in [26]. The resulting error margins are quite high, they are at least on the order of 50 %. They show that the particle densities obtained by emission spectroscopy represent only an order of magnitude, but the variations in dependence on phase, $\partial N_a/\partial \varphi$ and $\partial N_i/\partial \varphi$, provide a quite reliable information.

4.2. Absorption spectroscopy

The resulting radiance $I_\nu^{res}(y)$ composed of the radiance emitted by the UHP lamp $I_\nu^{abs,UHP}(y)$ and of the radiance emitted by the YAG lamp $I_\nu^{em,YAG}(y)$ is measured, when both lamps are operated simultaneously, in addition to the radiance emitted by the YAG lamp $I_\nu^{em,YAG}(y)$ alone. The difference between the two radiances

$$I_\nu^{abs,UHP}(y) = I_\nu^{res}(y) - I_\nu^{em,YAG}(y) = I_\nu^{UHP}(y) \exp \left[- \int_{x=-R/2}^{x=+R/2} \alpha(\nu, x, y) dx \right] \quad (2)$$

provides the absorption of the UHP back light $I_\nu^{UHP}(y)$ by the lamp plasma being given by the integral over the frequency-dependent local absorption coefficient $\alpha(\nu, \vec{r})$ along the optical path within the lamp, called optical depth τ . $I_\nu^{abs,UHP}(y)$ is recorded in a distance $z = d$ from the electrode tip along the lateral coordinate y . R is the discharge radius. A plot of $I_\nu^{abs,UHP}$ in dependence on λ for a fixed value of y may show a dip corresponding to the profile of the absorbing line. The undisturbed intensity of the UHP back light $I_\nu^{UHP}(y)$ is not measured separately but determined by an interpolation of the course of $I_\nu^{UHP}(y)$ between the wings of the absorption dip. An example showing a dip being formed by a Ce atom resonance line emitted by the YAG lamp seeded with

Figure 3: Example for the absorbed $I_{\nu}^{abs,UHP}$ (—) and interpolated I_{ν}^{UHP} (···) UHP back light at a Ce atom resonance line at $\lambda = 577.36$ nm measured $125 \mu\text{m}$ in front of the upper electrode. Parameter: CeI_3 , electrode diameter $d_E = 0.36$ mm, electrode length $l_E = 5$ mm, $i = 0.8$ A switched-dc

CeI_3 and the extrapolation of I_{ν}^{UHP} is given in figure 3. The advantage of the fitting procedure is a proportion $I_{\nu}^{UHP}(y)/I_{\nu}^{abs,UHP}(y)$, which is independent of fluctuations of the UHP back light and does not depend on the properties of the YAG lamp tube and their changes by temperature effects [20].

The optical depth $\tau(\nu, y)$ is calculated according to

$$\tau(\nu, y) = \int_{x=-R/2}^{x=+R/2} \alpha(\nu, x, y) dx = \ln \left(\frac{I_{\nu}^{UHP}(y)}{I_{\nu}^{abs,UHP}(y)} \right). \quad (3)$$

By an integration of the absorption coefficient $\alpha(\nu)$ with respect to the frequency ν a so called line absorption coefficient α_L is defined:

$$\alpha_L = \int_{\Delta\nu} \alpha(\nu) d\nu = N_l \frac{e^2}{4\pi\epsilon_0} \frac{\pi}{m_e c_0} f_{lu}. \quad (4)$$

N_l is the population density of the absorbing atomic state and f_{lu} the absorption oscillator strength of the specific optical transition, the other symbols have the usual meaning. α_L can be related to the measured absorption by an integration of the optical depth τ over a frequency interval $\Delta\nu$, which comprehends the absorption dip. By an inverse Abel transformation of

$$\int_{\Delta\nu} \tau(\nu, y) d\nu = \int_{\Delta\lambda} \tau(\lambda, y) \frac{c_0}{\lambda^2} d\lambda = \int_{x=-R/2}^{x=+R/2} \alpha_L(x, y) dx \quad (5)$$

the radial line absorption coefficient $\alpha_L(r)$ is obtained and with it the radial density distribution $N_l(r)$ of the absorbing atomic state if the discharge is rotational symmetric.

If N_l is the ground state of an atomic resonance line the total atomic density $N_a(r)$ can be calculated from:

$$N_a(r) = N_l(r) \frac{Q_a(T_{pl})}{g_l} = \frac{\alpha_L(r)}{f_{lu}} \frac{4\pi\epsilon_0}{e^2} \frac{m_e c_0}{\pi} \frac{Q_a(T_{pl})}{g_l}. \quad (6)$$

g_l is the statistical weight of the atomic ground state and Q_a the corresponding atomic partition function.

$\lambda = 577.36 \text{ nm}$
$f = 5.492 \cdot 10^{-3}$
$g_0 = 9$

Table 7: Spectroscopic data of the *Ce* resonance line [38] for the calculation of *Ce* atom density $N_{a,Ce}$

The *Ce* resonance line at $\lambda = 577.36 \text{ nm}$ is chosen to determine the *Ce* atom density $N_{a,Ce}(r)$ within the YAG lamp seeded with CeI_3 . An interference filter with a centre wavelength of 577 nm and a bandwidth of 10 nm FWHM is used to avoid a distracting irradiation of the YAG lamp by the UHP lamp. The atom density $N_{a,Ce}(r)$ is evaluated from α_L taking into account the spectroscopic data of table 7 and the partition function $Q_a(T_{pl})$ of the *Ce* atoms. It is calculated using the atomic data given in [38]. The absorption by the wings of the mercury lines at 576.96 nm and 579.07 nm is eliminated by using the extrapolated value of I_ν^{UHP} as a reference.

As an example $N_{a,Ce}(r)$ obtained by a measurement at a switched-dc current of 0.8 A at 10 Hz within the cathodic phase at phase angle $\varphi = 7\pi/5$ is presented in figure 4.

Figure 4: Radial *Ce* atom density $N_{a,Ce}(r)$ measured $125 \mu\text{m}$ in front of the upper electrode. Parameter: CeI_3 , electrode diameter $d_E = 0.36 \text{ mm}$, electrode length $l_E = 5 \text{ mm}$, $i = 0.8 \text{ A}$ switched-dc, 10 Hz, $\varphi = 7\pi/5$ (cathodic phase)

The logarithmic derivative of equation 6 is used to estimate the error margins of $N_{a,Ce}$:

$$\left| \frac{\Delta N_{a,Ce}}{N_{a,Ce}} \right| = \left| \frac{\Delta \alpha_L}{\alpha_L} \right| + \left| \frac{\Delta f_{lu}}{f_{lu}} \right| + \left| \frac{\partial \ln Q_{a,Ce}}{\partial \ln T_{pl}} \frac{\Delta T_{pl}}{T_{pl}} \right|. \quad (7)$$

The line absorption coefficient α_L may be afflicted with an error of the order of 20 % mainly by reason of the inverse Abel transformation, which reacts, especially on the axis, quite sensitive on deviations from symmetry of the lateral distribution of the integrated optical depth. The knowledge of the oscillator strength f_{lu} is not better than 10 %. The error margin of the plasma temperature, which is multiplied in equation 7 by $\partial \ln Q_{a,Ce} / \partial \ln T_{pl} \approx 1$, is of the order of 4 %. The resulting error margin is of the order of $|\Delta N_{a,Ce} / N_{a,Ce}| \cdot 100 \approx 35 \%$, which is much lower than the error margins of the particle densities determined by emission spectroscopy. This means that the absorption spectroscopy provides, different to the emission spectroscopy, quantitative information on particle densities within the YAG lamp.

A first discussion of the broadband absorption spectroscopy with an UHP lamp is given in [20, 31] while first results by means of this method are presented for YAG lamps seeded with DyI_3 in [21, 31] and with CeI_3 in [31, 40].

5. Estimation of the Cs ion density by SAHA equation

A spectroscopic measurement of the Cs ion density $N_{i,Cs}$ within the YAG lamp seeded with CsI is nearly impossible, since the energy gap between the ion ground state and the lowest excited state, which emits lines in the visible spectral range ($\lambda_{1,2,3,4} = 492.57, 522.70, 527.40, 537.10$ nm [41]), is very large. It amounts to $E_{i,ex} = 15.68$ eV, so that its population and with it the intensity of the ion lines is extremely low for plasma temperatures of the order of 7000 K in the lamp. Alternatively $N_{i,Cs}$ may be evaluated by inserting the Cs atom density $N_{a,Cs}$ and the plasma temperature T_{pl} into the SAHA equation for caesium $S_{Cs}(T_{pl})$, using the fact that LTE is established at the measuring point within the lamp plasma:

$$\begin{aligned} S(T) &= \frac{N_{i,Cs} N_e}{N_{a,Cs}} \\ &= \frac{Q_{i,Cs}(T_{pl})}{Q_{a,Cs}(T_{pl})} \frac{2(2\pi m_e k_b T_{pl})^{3/2}}{h^3} \exp\left(-\frac{E_{i,Cs}}{k_b T_{pl}}\right). \end{aligned} \quad (8)$$

But this raises the question whether the electron density N_e is equal to the Cs ion density $N_{i,Cs}$. The ionisation energy of caesium ($E_{i,Cs} = 3.893$ eV) is much lower than the ionisation energy of iodine ($E_{i,I} = 10.45$ eV) and of mercury ($E_{i,Hg} = 10.43$ eV). It is clear that the iodine ion density $N_{i,I}$ can be neglected compared to the Cs ion density $N_{i,Cs}$, if is taken into account that the corresponding atom densities within the ratio of the SAHA equations for iodine and caesium are of the same order of magnitude:

$$\frac{N_{i,I}}{N_{i,Cs}} = \frac{N_{a,I}}{N_{a,Cs}} \frac{Q_{i,I} Q_{a,Cs}}{Q_{a,I} Q_{i,Cs}} \exp\left(-\frac{E_{i,I} - E_{i,Cs}}{k_b T_{pl}}\right). \quad (9)$$

But the density of Hg atoms, $N_{a,Hg}$, is three orders of magnitude higher than the density of I atoms so that the density of the Hg ions $N_{i,Hg}$ may be comparable to that of the Cs ions $N_{i,Cs}$, as is shown by a relation similar to equation 9, in spite of a much lower ionisation degree of mercury compared to caesium.

Due to quasi neutrality the electron density N_e is determined in the YAG lamp filled with Hg and CsI by

$$N_e \approx N_{i,Cs} + N_{i,Hg} . \quad (10)$$

Combining equation 10 and the SAHA equations for caesium $S_{Cs}(T_{pl})$ (equation 8) and that for mercury $S_{Hg}(T_{pl})$, the ion densities $N_{i,Cs}$ and $N_{i,Hg}$ can be expressed by the corresponding atom densities according to:

$$N_{i,Cs} = \frac{S_{Cs}(T_{pl})N_{a,Cs}}{[S_{Hg}(T_{pl})N_{a,Hg} + S_{Cs}(T_{pl})N_{a,Cs}]^{1/2}} \quad (11)$$

$$N_{i,Hg} = \frac{S_{Hg}(T_{pl})N_{a,Hg}}{[S_{Cs}(T_{pl})N_{a,Cs} + S_{Hg}(T_{pl})N_{a,Hg}]^{1/2}} . \quad (12)$$

Results for $N_{i,Cs}$ and $N_{i,Hg}$ will be given in chapter 6.1. Equation 11 shows that the Cs ion density $N_{i,Cs}$ is reduced by the competing ionisation of Hg . According to equation 11 the error margins of $N_{i,Cs}$ may be still higher than those of the Cs atom density $N_{a,Cs}$:

$$\frac{\Delta N_{i,Cs}}{N_{i,Cs}} \geq \frac{\Delta N_{a,Cs}}{N_{a,Cs}} . \quad (13)$$

6. Results and discussion of measurements at the YAG lamps

Measurements are performed at YAG lamps which are operated with switched-dc current of 0.8 A and operating frequencies of 1, 10, 100, 500 Hz and 1 kHz. At most, measurements at 10 equidistant phase angles over one period are accomplished. For operating frequencies greater than 100 Hz it was often not possible to carry out more than one measurement per half period. In the subsequent figures, which present the phase resolved measuring results, the first half period ($\varphi = 0 - \pi$) is the anodic and the second half period ($\varphi = \pi - 2\pi$) the cathodic phase. Phase resolved results of the electrode tip temperature $T_{tip}(\varphi)$, plasma temperature $T_{pl}(\varphi)$ and density of atoms $N_a(\varphi)$ and ions $N_i(\varphi)$ are presented. The pyrometric measurements are performed at the upper electrode, all spectroscopic measurements at a distance of 125 μm in front of it. The reported values of $T_{pl}(\varphi)$, $N_a(\varphi)$ and $N_i(\varphi)$ are averages over a rotational symmetric cross section with the same diameter as the electrode.

6.1. YAG lamp seeded with CsI

Figure 5 shows the electrode tip temperature $T_{tip}(\varphi)$ of the upper electrode for different frequencies. The maximum values of $T_{tip}(\varphi)$ are at least 290 K below the melting point of tungsten of 3695 K. The courses of $T_{tip}(\varphi)$ demonstrate for $f < 100$ Hz a heating of the electrode within the anodic phase while in the cathodic phase a reduction of its heating is visible. The modulation diminishes with increasing frequency, but the resulting average value of $T_{tip}(\varphi)$ increases with frequency for frequencies of $f \geq 500$ Hz. It is obvious that a reduction of $T_{tip}(\varphi)$ of at least 200 K is induced by the Cs atoms and Cs ions within the discharge compared to a YAG lamp with Hg filling only being shown in figure 1(a) of the reference paper [26]. It amounts even 400 K for $f = 1$ kHz. But the increase of $T_{tip}(\varphi)$ with increasing frequency is a striking difference to the decrease of $T_{tip}(\varphi)$ in YAG lamps seeded with rare earth iodides as is shown in [26] figure 5(a) for DyI_3 and in section 6.2 for CeI_3 .

Figure 5: Electrode tip temperature $T_{tip}(\varphi)$ measured at the upper electrode over one period for various frequencies. Parameter: CsI, electrode diameter $d_E = 0.36$ mm, electrode length $l_E = 5$ mm, $i = 0.8$ A switched-dc

Figure 6(a) presents the plasma temperature $T_{pl}(\varphi)$ measured in front of the upper electrode for different frequencies. $T_{pl}(\varphi)$ is at least 700 K higher in the anodic phase than in the cathodic phase. $T_{pl}(\varphi)$ decreases in the anodic phase for $f \geq 500$ Hz. The considerably reduced plasma temperature in front of the cathode indicates an enhancement of the Cs density within the cathodic phase by cataphoresis. It is generated by the electric force on the Cs^+ ions and a counteracting pressure gradient of the Cs ion density. The density of the Cs ions and Cs atoms is coupled by charge exchange, ionisation and recombination processes. A flow of Cs atoms, which is propelled by a decline of Cs atoms in front of the cathode, compensates the Cs ion current towards the cathode. By reason of the low ionisation energy $E_i = 3.89$ eV of Cs only a low plasma temperature is required to generate a sufficiently high electron density N_e in front of the cathode. Similar courses of $T_{pl}(\varphi)$ were measured by Langenscheidt *et al* at a YAG

lamp seeded with NaI , TlI and DyI_3 [24]. The plasma temperature in front of the upper electrode $T_{pl}(\varphi)$ of a YAG lamp without any salt filling ([26] figure 2) or seeded with CeI_3 (figure 8(b)) shows a completely different behaviour for the same current amplitude and waveform. $T_{pl}(\varphi)$ is generally higher in these cases, moreover it is higher in the cathodic phase than in the anodic phase. In addition with increasing frequency a decrease of $T_{pl}(\varphi)$ independent of the phase is visible. Hence it is obvious that the ionisation energy E_i of the respective metal iodide has a distinct influence on $T_{pl}(\varphi)$.

The Hg ion density $N_{i,Hg}(\varphi)$, estimated with equation 12, is shown for different frequencies in figure 6(b). The course of $N_{i,Hg}(\varphi)$ is similar to the course of $T_{pl}(\varphi)$ (figure 6(a)): $N_{i,Hg}(\varphi)$ is up to 18 times higher within the anodic phase than within the cathodic phase where $N_{i,Hg}(\varphi)$ varies between $2 \cdot 10^{20} \text{ m}^{-3}$ and $4.5 \cdot 10^{21} \text{ m}^{-3}$. $N_{i,Hg}(\varphi)$ decreases simultaneously with $T_{pl}(\varphi)$ in the anodic phase for $f \geq 500 \text{ Hz}$. The course of $N_{i,Hg}(\varphi)$ reflects the influence of the mercury ionisation on N_e particularly in the anodic phase. Hence $N_{i,Hg}(\varphi)$ has to be taken into account referred to equation 10 when the Cs ion density $N_{i,Cs}(\varphi)$ is determined with SAHA equation.

Figure 7(a) shows the Cs atom density $N_{a,Cs}(\varphi)$ determined in front of the upper electrode for different frequencies. $N_{a,Cs}(\varphi)$ is lower by one order of magnitude in the anodic phase than in the cathodic phase. $N_{a,Cs}(\varphi)$ increases weakly in the anodic phase with increasing frequency and decreases by one order of magnitude in the cathodic phase. For higher operating frequencies ($f \geq 500 \text{ Hz}$) the density is nearly constant over time.

The Cs ion density $N_{i,Cs}(\varphi)$ being estimated with equation 11 is shown for different frequencies in figure 7(b). The values of $N_{i,Cs}(\varphi)$ are higher than the Cs atom density $N_{a,Cs}(\varphi)$ which is caused by the low ionisation energy E_i of Cs , but the trend is nearly the same. $N_{i,Cs}(\varphi)$ is according to $N_{a,Cs}(\varphi)$ in the anodic phase by one order of magnitude lower than in the cathodic phase. $N_{i,Cs}(\varphi)$ decreases in the cathodic phase and increases in the anodic phase with increasing frequency, except for $f = 1 \text{ kHz}$. Also an assimilation of $N_{i,Cs}(\varphi)$ takes place with increasing frequency within both phases.

The increase of $N_{a,Cs}(\varphi)$ (figure 7(a)) and $N_{i,Cs}(\varphi)$ (figure 7(b)) in the cathodic phase demonstrates the existence of a Cs ion current towards the cathode. It may not only substitute in part the thermionic electron emission of the cathode but above all produce a monolayer of Cs atoms on the surface of the cathode. This layer may reduce the work function and thereby the temperature of the electrode. According to numerical calculations given in [4] the reduction of $T_{tip}(\varphi)$ is only marginally induced by a lowering of the plasma temperature $T_{pl}(\varphi)$ caused by the Cs vapour in front of the cathode, but mainly by a reduction of the work function ϕ by a Cs monolayer. Its formation becomes obvious by comparing the electrode tip temperatures $T_{tip}(\varphi)$ in figure 5 and figure 1(a) of [26]. Furthermore, the missing formation of an emitter spot within the cathodic phase is an indication for a moderate Cs ion current density in front of the cathode [20, 24]. The decrease of $N_{a,Cs}(\varphi)$ and $N_{i,Cs}(\varphi)$ in the anodic phase is caused by the

reversal of the *Cs* ion current. But this takes place with a finite time constant, as is indicated by the increase of the *Cs* atom and *Cs* ion density in front of the anode with increasing frequency. Nevertheless figure 5 reveals an increase of the average electrode tip temperature with increasing frequency. This may result from a decreasing phase averaged coverage of the electrode surface with emitter atoms for increasing frequencies due to the low adsorption energy E_a of *Cs* of 3.37 eV (table 1). Therefore an expansion of the emitter effect to the anodic phase with increasing frequency, which may effect a reduction of the average work function, does not take place.

6.2. YAG lamp seeded with CeI_3

Figure 8(a) shows $T_{tip}(\varphi)$ of the upper electrode for different frequencies. Similar to the course of $T_{tip}(\varphi)$ of a YAG lamp seeded with *CsI* (figure 5) a heating of the electrode in the anodic phase and a reduction of its heating in the cathodic phase takes place. This change with polarity diminishes with increasing frequency. Additionally the maximal values of $T_{tip}(\varphi)$ given in figure 8(a) are at least 390 K below the melting point of tungsten. A comparison with $T_{tip}(\varphi)$ of a YAG lamp with *Hg* filling only (given in figure 1(a) of reference [26]) confirms a general reduction of $T_{tip}(\varphi)$ of at least 300 K effected by the presence of *Ce* atoms and *Ce* ions in the arc plasma. By comparing the courses of $T_{tip}(\varphi)$ of figure 5 and 8(a) it is visible that for 1, 10 and 100 Hz the temperature values of the YAG lamp seeded with *CsI* are below $T_{tip}(\varphi)$ of the lamp seeded with CeI_3 , only for 1 Hz between $\varphi = \pi/2$ and $\varphi = \pi$ a more pronounced temperature increase is observed for a lamp seeded with *CsI*. But the most important difference to figure 5 is a decrease of $T_{tip}(\varphi)$ with increasing frequency. For $f = 1$ kHz a reduction of $\Delta T_{tip}(\varphi) = 600$ K is induced by a seeding with CeI_3 compared to a YAG lamp operated with a pure mercury vapour atmosphere.

$T_{pl}(\varphi)$, measured in front of the upper electrode, is presented in figure 8(b) for different frequencies. The values of $T_{pl}(\varphi)$ decrease slightly with increasing frequency. $T_{pl}(\varphi)$ is higher in the cathodic phase than in the anodic phase. Similar courses of $T_{pl}(\varphi)$ were measured by Langenscheidt *et al* at a YAG lamp seeded only with DyI_3 , being shown in figure 12 and figure 13 of reference [24]. It reflects a higher power requirement to generate *Ce* ions instead of *Cs* ions by reason of the higher ionisation energy of *Ce*. At 1 kHz the courses of $T_{pl}(\varphi)$ in the anodic and cathodic phase converge. $T_{pl}(\varphi)$ is at most 150 K higher in comparison to a YAG lamp with Hg filling only ([26] figure 2) while the course of $T_{pl}(\varphi)$ is similar. The difference between the plasma temperatures in both lamps is within the error margin of approximately 300 K.

Figure 9(a) shows courses of the *Ce* atom density $N_{a,Ce}(\varphi)$ while figure 9(b) represents courses of the *Ce* ion density $N_{i,Ce}(\varphi)$ in front of the upper electrode for different frequencies. The *Ce* atom density as well as the *Ce* ion density is higher in the cathodic than in the anodic phase. But the difference of the *Ce* atom density

within the cathodic and anodic phase is distinctly smaller than in YAG lamps seeded with CsI (figure 7(a)) or with DyI_3 (as is shown in figure 3 and figure 4 of reference [26]). Moreover the Ce atom density $N_{a,Ce}(\varphi)$ and ion density $N_{i,Ce}(\varphi)$ are higher than the corresponding Cs densities. Especially they are of the order of ten higher than the Dy atom and ion densities (being shown in figure 3 of reference [26]). Both Ce densities decrease with increasing frequency in the cathodic phase. But in the anodic phase a general trend is not visible for the Ce atom density $N_{a,Ce}(\varphi)$ as well as for the Ce ion density $N_{i,Ce}(\varphi)$. $N_{i,Ce}(\varphi)$ increases within the cathodic phase with a time constant on the order of 10 ms and $N_{a,Ce}(\varphi)$ with an extended time constant of 20 ms. Accordingly at operating frequencies above several ten Hertz the maximum values of $N_{a,Ce}(\varphi)$ and $N_{i,Ce}(\varphi)$ are lowered with increasing frequency. The variation of $N_{i,Ce}(\varphi)$ and the delayed variation of $N_{a,Ce}(\varphi)$ in dependence on phase and on operating frequency demonstrates that Ce is transported cataphoretically in front of the electrode. A Ce atom monolayer is deposited on the electrode surface by a Ce ion current from the plasma to the cathode. It reduces the work function and therefore $T_{tip}(\varphi)$ which is proved by comparing figure 8(a) with figure 1(a) of [26]. The reduction of $N_{a,Ce}(\varphi)$ and $N_{i,Ce}(\varphi)$ in the anodic phase is produced by a reversal of the Ce ion current. $N_{a,Ce}(\varphi)$ and $N_{i,Ce}(\varphi)$ are nearly constant over time for higher frequencies indicating that the Ce ions are too immobile to follow the frequency above 500 Hz. They remain directly in front of the electrode, recombine and form a layer of Ce atoms on the electrode surface even during the anodic phase. Thus the emitter effect remains active also within the anodic phase and because of this $T_{tip}(\varphi)$ decreases with increasing frequency (figure 8(a)).

7. Conclusion

In the YAG lamp seeded with CsI a cathodic gas phase emitter effect due to a Cs ion current is observed at low frequencies ($f < 500$ Hz), but the emitter effect does not overlap onto the anodic phase with increasing frequency. This is caused by an insufficient coverage of the electrode surface with Cs atoms within the anodic phase due to the low adsorption energy E_a of Cs ($E_a = 3.37$ eV) within the anodic phase. It leads to an increase of the averaged electrode tip temperature $T_{tip}(\varphi)$ with increasing frequency. A direct indication that the layer of Cs atoms is removed within the anodic phase is the increase of $T_{tip}(\varphi)$ at the end of the anodic phase for $f = 1$ Hz up to 3400 K, which exceeds the otherwise higher electrode tip temperature $T_{tip}(\varphi)$ of a YAG lamp seeded with CeI_3 by 100 K. Though, the cathodic gas phase emitter effect reduces the work function and temperature of the electrode and increases the lifetime of the lamp.

In the YAG lamp seeded with CeI_3 a gas phase emitter effect is produced at low frequencies ($f < 500$ Hz) mainly by a Ce ion current in the cathodic phase whereas it disappears with a time constant of some milliseconds within the anodic phase. The reduction of the electrode tip temperature $T_{tip}(\varphi)$ is at low frequencies less pronounced than within a YAG lamp seeded with CsI but more pronounced than within a lamp seeded with DyI_3 . The difference between the Ce and Cs lamp can be attributed to the

lower work function ϕ of the *Cs* monolayer compared to that of *Ce*, but the difference between the *Ce* and *Dy* lamp can be attributed, at least in part, to the higher adsorption energy E_a of *Ce* compared to *Dy* on tungsten. The higher adsorption energy E_a of *Ce* may also be the reason for a higher *Ce* atom and ion density in front of the electrode and a weaker modulation of the *Ce* particle density in dependence on polarity compared to *Dy*. Moreover it has to be taken into account that the spectroscopic measurements at a distance of $125\ \mu\text{m}$ from the electrode tip reflect only partially the density variation immediately in front of the electrode.

At higher operating frequencies the reduction of the electrode tip temperature $T_{\text{tip}}(\varphi)$ is most pronounced within the *Ce* lamp, less distinct within the *Dy* lamp and even reversed within the *Cs* lamp. It reflects the decrease of the adsorption energy E_a from *Ce* to *Dy* and *Cs* which corresponds to a successive reduction of the life time of the *Ce*, *Dy* and *Cs* monolayer. The emitter effect and with it the reduction of the electrode tip temperature overlaps to the anodic phase at higher frequencies with increasing life time of the monolayer, e.g. for lamps seeded with CeI_3 or DyI_3 but not for lamps seeded with CsI in spite of an increase of the *Cs* ion density in front of the anode with increasing frequency.

The findings are another test of the hypothesis that in HID lamps emitter material can be deposited on the surface of hot tungsten electrodes by an ion current from the arc plasma to the cathode. Appropriate materials are able to reduce the work function of tungsten by the formation of an atomic monolayer and with it the electrode temperature.

It supplements the investigation of the gas phase emitter effect of *Dy* given in a preceding paper [26]. In this paper not only a correlation between an enhanced *Dy* ion density in front of the electrode and a reduced electrode temperature was demonstrated. It was also confirmed by an additional seeding of the YAG lamp with *TlI* that not the substitution of thermionic electron emission by an ion current but a reduced work function is responsible for the temperature reduction of the electrode. The vapour pressure of *TlI* is much higher than that of DyI_3 . The metallic *Tl* exhibits a much higher work function than metallic *Dy*, but the ionisation energy of *Tl* vapour ($E_i = 6.11\ \text{eV}$) is nearly the same as that of *Dy* vapour. Therefore the current transferred by metal ions in front of the cathode within a lamp additionally seeded with *TlI* cannot be smaller than in a lamp seeded only with DyI_3 . In spite of that the emitter effect is suppressed by the thallium additive in accordance with its higher work function.

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(a) Plasma temperature

(b) Hg ions (SAHA equation)

Figure 6: Plasma temperature $T_{pl}(\varphi)$ and mercury ion density $N_{i,Hg}(\varphi)$ at a distance of $125\mu\text{m}$ in front of the upper electrode over one period for various frequencies. Parameter: CsI , electrode diameter $d_E = 0.36\text{ mm}$, electrode length $l_E = 5\text{ mm}$, $i = 0.8\text{ A}$ switched-dc

(a) Cs atoms

(b) Cs ions (SAHA equation)

Figure 7: Caesium atom density $N_{a,Cs}(\varphi)$ and estimated ion density $N_{i,Cs}(\varphi)$ over one period for various frequencies at a distance of $125\mu\text{m}$ in front of the upper electrode. Parameter: CsI , electrode diameter $d_E = 0.36\text{ mm}$, electrode length $l_E = 5\text{ mm}$, $i = 0.8\text{ A}$ switched-dc

(a) Electrode tip temperature

(b) Plasma temperature

Figure 8: Electrode tip temperature $T_{tip}(\varphi)$ measured at the upper electrode over one period for various frequencies and plasma temperature $T_{pl}(\varphi)$ measured over one period for various frequencies at a distance of $125\ \mu\text{m}$ in front of the upper electrode. Parameter: CeI_3 , electrode diameter $d_E = 0.36\ \text{mm}$, electrode length $l_E = 5\ \text{mm}$, $i = 0.8\ \text{A}$ switched-dc

(a) Ce atoms

(b) Ce ions

Figure 9: Cerium atom density $N_{a,Ce}(\varphi)$ and ion density $N_{i,Ce}(\varphi)$ over one period for various frequencies at a distance of $125\ \mu\text{m}$ in front of the upper electrode. Parameter: CeI_3 , electrode diameter $d_E = 0.36\ \text{mm}$, electrode length $l_E = 5\ \text{mm}$, $i = 0.8\ \text{A}$ switched-dc